



### **Dual USB High-Side Power Switch**

#### **FEATURES**

- 110mΩ (5V Input) High-Side MOSFET Switch.
- 500mA Continuous Load Current per Channel.
- 110μA Typical On-State Supply Current.
- 1μA Typical Off-State Supply Current.
- Current-Limit / Short Circuit Protection.
- Thermal Shutdown Protection under Overcurrent Condition.
- Undervoltage Lockout Ensures that Switch is off at Start Up.
- Output can be Forced Higher than Input (Off-State).
- Open-Drain Fault Flag.
- Slow Turn ON and Fast Turn OFF.
- Enable Active-High or Active-Low.

#### **APPLICATIONS**

- USB Power Management.
- Hot Plug-In Power Supplies.
- Battery-Charger Circuit.

#### DESCRIPTION

The AIC1526 is a dual high-side power switch for self-powered and bus-powered Universal Serial Bus (USB) applications. One high-side switch is a MOSFET with  $110 \text{m}\Omega$  R<sub>DS(ON)</sub>, which meets USB voltage drop requirements for maximum transmission wire length.

Multi-purpose open-drain fault flag output indicates over-current limiting, thermal shutdown, or undervoltage lockout for each channel. Output current is typically limited to 1A, well below the 5A safety requirement, and the thermal shutdown function independently controls each channel under overcurrent condition.

Guaranteed minimum output rise time limits inrush current during hot plug-in, minimizing EMI and preventing the voltage at upstream port from dropping excessively.

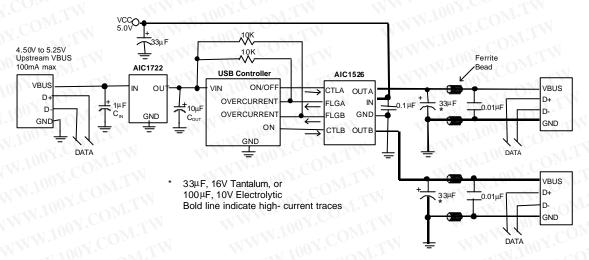
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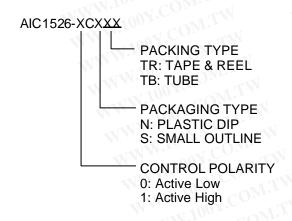


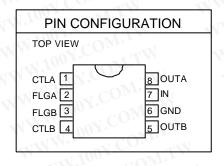
#### TYPICAL APPLICATION CIRCUIT



Two-Port Self-Powered Hub

#### ORDERING INFORMATION





Example: AIC1526-0COTR

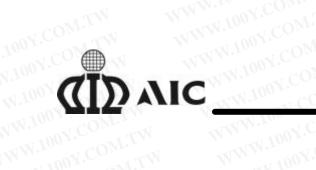
→ Active Low Version in SO-8 Package & Taping & Reel Packing Type (CN is not available in TR packing)



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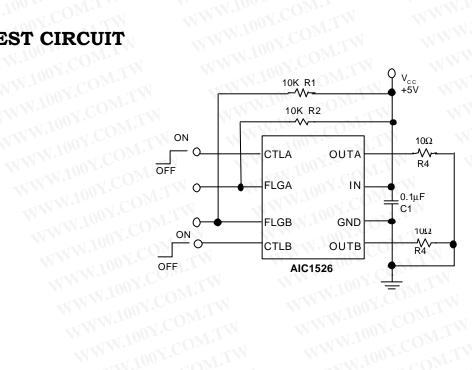




## WWW.100X.COM.TW ■ ABSOLUTE MAXIMUM RATINGS

Supply Voltage (V <sub>IN</sub> )	7.0V
Fault Flag Voltage (V <sub>FLG</sub> )	7.0V
Fault Flag Current (I <sub>FLG</sub> )	50mA
Control Input (V <sub>CTL</sub> )	0.3V ~15V
Operating Temperature Range	40°C~85°C
Storage Temperature Range	65°C ~ 150°C

## JY.COM.TW **TEST CIRCUIT** WWW.100Y.COM







# ■ ELECTRICAL CHARACTERISTICS (V<sub>IN</sub>= 5V, T<sub>A</sub>=25°C, unless otherwise specified.)

PARAMETERS	CONDITIONS	MIN.	TYP.	MAX.	UNIT
Supply Current	V <sub>CTL</sub> =Logic "0" , OUT=Open V <sub>CTL</sub> =Logic "1" , OUT=Open	NAMA	0.75 110	5 160	μА
Control Input Voltage	V <sub>CTL</sub> =Logic "0" V <sub>CTL</sub> =Logic "1"	2.4	1.100 X	C0.8	V
Control Input Current	V <sub>CTL</sub> =Logic "0" V <sub>CTL</sub> =Logic "1"	M	0.01 0.01	y.com	μΑ
Control Input Capacitance	WWW. 100Y. CONT.TW		111	001.00	pF
Output MOSFET Resistance	WWW.TOOY.CO.TY		110	150	$m\Omega$
Output Turn-On Rise Delay	$R_L = 10\Omega$ each Output	V.	100	100Y.C	μS
Output Turn-On Rise Time	$R_L = 10\Omega$ each Output	N	1000	2500	μS
Output Turn-Off Delay	$R_L = 10\Omega$ each Output	TW	0.8	20	μS
Output Turn-Off Fall Time	$R_L = 10\Omega$ each Output	TW	0.7	20	μS
Output Leakage Current	WWW.IOOX.CO	TW	W	10	μА
Current Limit Threshold	WWW.IOOV.CO	0.6	1.0	1.25	A
Overtemperature Shutdown Threshold	T <sub>J</sub> Increasing T <sub>J</sub> Decreasing	OM.TW	135 125	MMM.	°C
Error Flag Output Resistance	$V_{IN} = 5V$ , $I_L = 10$ mA $V_{IN} = 3.3V$ , $I_L = 10$ mA	COM.T	10 15	25 40	Ω
Error Flag Off Current	$V_{FLG} = 5V$	COM	0.01	1	μΑ
UVLO Threshold	V <sub>IN</sub> Increasing V <sub>IN</sub> Decreasing	ON.CON	2.6 2.4	N	V





#### TYPICAL PERFORMANCE CHARACTERISTICS

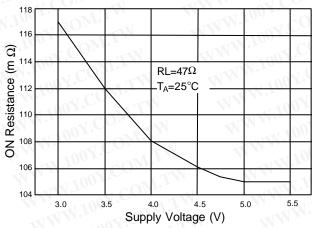


Fig. 1 ON Resistance vs. Supply Voltage

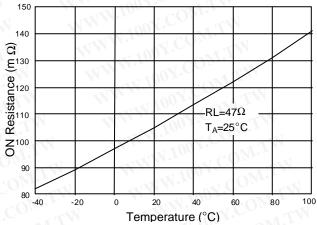


Fig. 2 Output On Resistance vs. Temperature

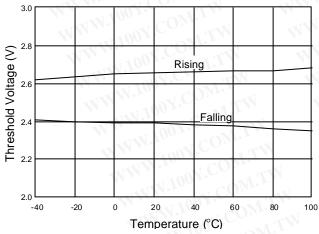


Fig. 3 UVLO Threshold Voltage vs. Temperature

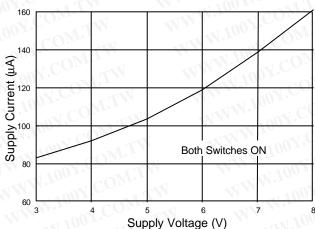


Fig. 4 ON-State Supply Current vs. Supply Voltage

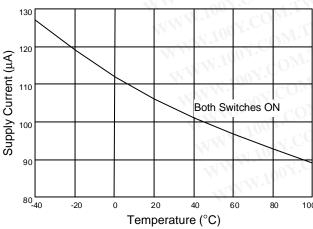
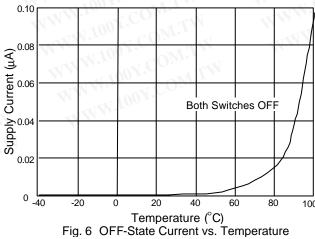


Fig. 5 ON State Current vs. Temperature







#### **■ TYPICAL PERFORMANCE CHARACTERISTICS (Continued)**

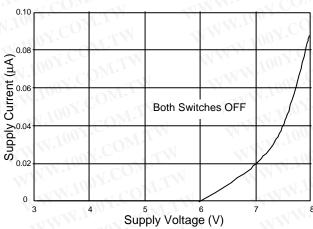
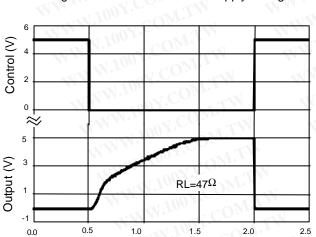


Fig. 7 OFF-State Current vs. Supply Voltage



Time (mS)
Fig. 9 Turn-On, Turn-Off Characteristics

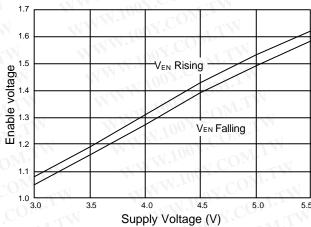


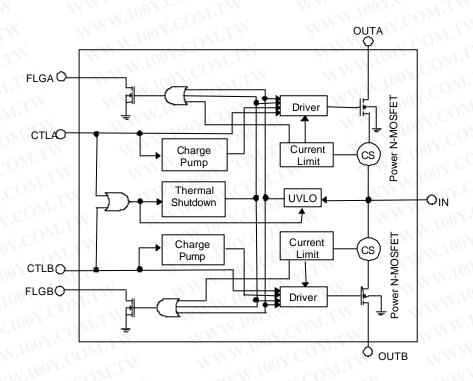
Fig. 8 Control Threshold vs. Supply Voltage







#### **■ BLOCK DIAGRAM**



#### ■ PIN DESCRIPTIONS

PIN 1: CTLA - TTL compatible control input. It controls the turn-on/turn-off of channel A MOSFET. Active high for AIC1526-1 and active low for AIC1526-0.

PIN 2: FLGA - An active-low and open-drained fault flag output for channel A. It can indicate current limit if CTLA is active. In normal mode operation (CTLA or/and CLTB is active), it also can indicate thermal shutdown or undervoltage.

PIN 3: FLGB - An active-low and opendrained fault flag output for channel B. It can indicate current limit if CTLB is active. In normal mode operation (CTLB or/and CLTA is active), it also can indicate thermal

shutdown or undervoltage.

PIN 4: CTLB - TTL compatible control input. It controls the turn-on/turn-off of channel B MOSFET. Active High for AIC1526-1 and active low for AIC1526-0.

PIN 5: OUTB - Channel B MOSFET switch output.

PIN 6: GND - Chip power ground.
PIN 7: IN - Power supply input.

PIN 8: OUTA - Channel A MOSFET switch output.





#### APPLICATION INFORMATION

#### Error Flag

An open-drained output of an N-channel MOSFET, the FLG output is pulled low to signal the following fault conditions: input undervoltage, output current limit, and thermal shutdown.

#### Current Limit

The current limit threshold is preset internally. It protects the output MOSFET switches from damage due to undesirable short circuit conditions or excess inrush current often encountered during hot plug-in. The low limit of the current limit threshold of the AIC1526 allows a minimum current of 0.5A through the MOSFET switches. A current limit condition will signal the error flag.

#### Thermal Shutdown

When the chip temperature exceeds 135°C for any reason other than overcurrent fault of either one of the two MOSFET switches, the thermal shutdown function turns off both MOSFET switches and signal the error flag. A hysteresis of 10°C prevents the MOSFETs from turning back on until the chip temperature drops to below 125°C. However, if thermal shutdown is triggered by chip temperature rise due to overcurrent fault condition of either one of the MOSFET switches, the thermal shutdown function will only turn off the switch that is in overcurrent condition and the other switch can still remain its normal operation. In other words, the thermal shutdown function of the two switches is independent of each other in

the case of overcurrent fault.

#### Supply Filtering

A  $0.1\mu F$  to  $1\mu F$  bypass capacitor from IN to GND, located near the device, is strongly recommended to control supply transients. Without a bypass capacitor, an output short may cause sufficient ringing on the input (from supply lead inductance) to damage internal control circuitry.

#### Transient Droop Requirements

USB support dynamic attachment (hot plug-in) of peripherals. A current surge is caused by the input capacitance of downstream device. Ferrite beads are recommended in series with all power and ground connector pins. Ferrite beads reduce EMI and limit the inrush current during hotattachment by filtering high-frequency signals.

#### Short Circuit Transient

Bulk capacitance provides the short-term transient current needed during a hot-attachment event. With a  $33\mu F$ , 16V tantalum or  $100\mu F$ , 10V electrolytic capacitor mounted close to downstream connector per port should provide transient drop protection.

#### Printed Circuit Layout

The power circuitry of USB printed circuit boards requires a customized layout to maximize thermal dissipation and to minimize voltage drop and EMI.

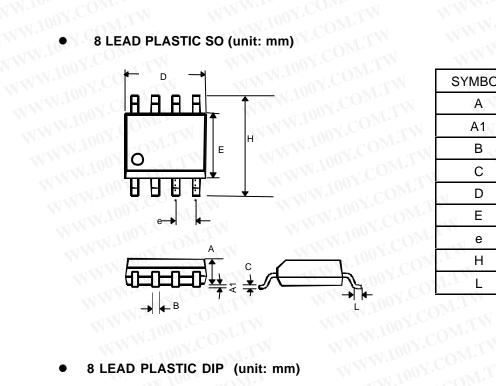


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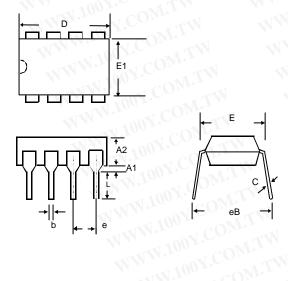


#### PHYSICAL DIMENSION



SYMBOL	MIN	MAX
A	1.35	1.75
A1	0.10	0.25
В	0.33	0.51
C	0.19	0.25
D	4.80	5.00
E	3.80	4.00
е	1.27(TYP)	
Н	5.80	6.20
T.A.	0.40	1.27

#### 8 LEAD PLASTIC DIP (unit: mm)



		N N
SYMBOL	MIN	MAX
A1 (0)	0.381	WY
A2	2.92	4.96
1.10b	0.35	0.56
W.1C0.	0.20	0.36
DOOX.	9.01	10.16
E100	7.62	8.26
E1 100	6.09	7.12
е	2.54	(TYP)
eB	107.Co	10.92
WENT	2.92	3.81